NSN 5961-00-539-1063

Transistor - Page 1 of 1



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Overall Height: Setween 0.188 inches and 0.201 inches Overall Diameter: Setween 0.203 inches and 0.230 inches Internal Configuration: Field effect Features Provided: Hermetically sealed case Semiconductor Material: Silicon Voltage Rating In Volts Per Characteristic: 15.0 breakdown voltage, drain-to-source, with all other terminals short-circuited to source and 10.0 breakdown voltage, gate-to-souvith all other terminals short-circuited to source	
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vith all other terminals short-circuited to source	ırce,
Ferminal Type And Quantity:	
uninsulated wire lead	
Shelf Life:	
N/a	
Jnit Of Measure:	
-	
Demilitarization:	
No	
Filg:	
A110a0	